

HD74ALVC162834A

18-bit Universal Bus Driver with 3-state Outputs and Inverted Latch Enable

HITACHI

ADE-205-293B (Z)

Rev. 2
Oct. 2001

Description

The HD74ALVC162834A is an 18-bit universal bus driver designed for 2.3 V to 3.6 V V_{cc} operation.

Data flow from A to Y is controlled by the output enable (\overline{OE}). The device operates in the transparent mode when the latch enable (\overline{LE}) is low. When \overline{LE} is low, the A data is latched if the clock (CLK) input is held at a high or low logic level. If the \overline{LE} is high, the A data is stored in the latch/flip flop on the low to high transition of CLK. When \overline{OE} is high, the outputs are in the high impedance state.

To ensure the high impedance state during power up or power down, \overline{OE} should be tied to V_{cc} through a pullup resistor; the minimum value of the resistor is determined by the current sinking capability of the driver.

All outputs, which are designed to sink up to 12 mA, include series dumping resistors to reduce overshoot and undershoot.

Features

- Supports PC133 and meets "PC SDRAM registered DIMM specification, Rev. 1.1"
- $V_{cc} = 2.3\text{ V to }3.6\text{ V}$
- Typical V_{ol} ground bounce $< 0.8\text{ V}$ ($@V_{cc} = 3.3\text{ V}$, $T_a = 25^\circ\text{C}$)
- Typical V_{oh} undershoot $> 2.0\text{ V}$ ($@V_{cc} = 3.3\text{ V}$, $T_a = 25^\circ\text{C}$)
- High output current $\pm 12\text{ mA}$ ($@V_{cc} = 3.0\text{ V}$)
- All outputs have series dumping resistors, so no external resistors are required
- t_{pd} (CLK to Y) = 3.5 ns (Max) ($@V_{cc} = 3.3\pm 0.3\text{ V}$, $C_L = 50\text{ pF}$, $T_a = 0\text{ to }85^\circ\text{C}$)
- t_{pd} (CLK to Y) = 2.5 ns (Max) ($@V_{cc} = 3.3\pm 0.3\text{ V}$, $C_L = 30\text{ pF}$, $T_a = 0\text{ to }85^\circ\text{C}$)
- Package type

Package type	Package code	Package suffix	Taping code
TSSOP-56pin	TTP-56DAV	T	EL(1000pcs / Reel)
TVSOP-56pin	TTP-56DBV	N	EL(1000pcs / Reel)

Function Table**Inputs**

$\overline{\text{OE}}$	$\overline{\text{LE}}$	CLK	A	Output Y
H	X	X	X	Z
L	L	X	L	L
L	L	X	H	H
L	H	↑	L	L
L	H	↑	H	H
L	H	L or H	X	Y_0^{*1}

H : High level

L : Low level

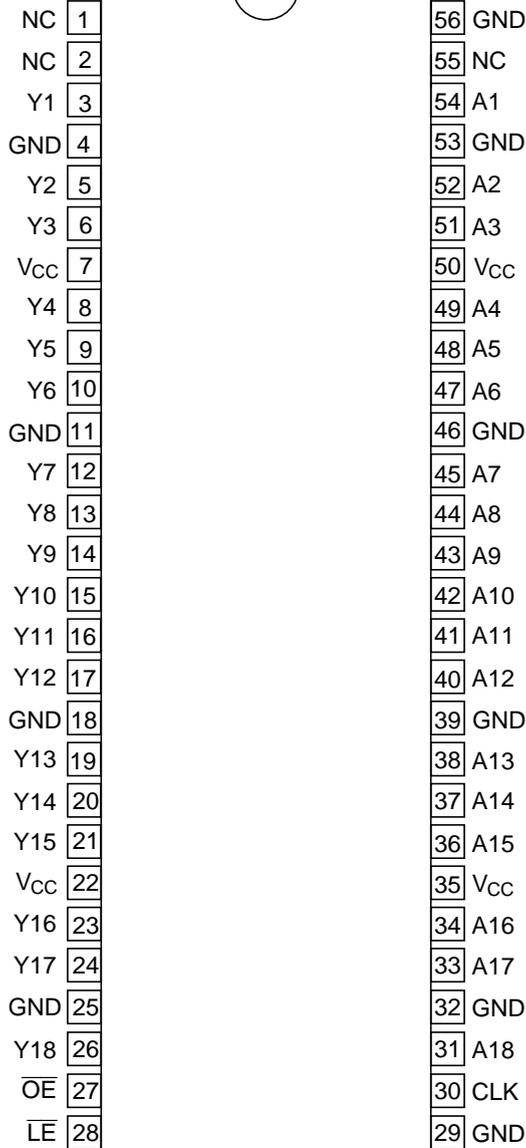
X : Immaterial

Z : High impedance

↑ : Low to high transition

Note: 1. Output level before the indicated steady-state input conditions were established.

Pin Arrangement



(Top view)

Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions
Supply voltage range	V_{CC}	-0.5 to 4.6	V	
Input voltage range ¹	V_I	-0.5 to 4.6	V	
Output voltage range ^{1, 2}	V_O	-0.5 to $V_{CC}+0.5$	V	
Input clamp current	I_{IK}	-50	mA	$V_I < 0$
Output clamp current	I_{OK}	± 50	mA	$V_O < 0$ or $V_O > V_{CC}$
Continuous output current	I_O	± 50	mA	$V_O = 0$ to V_{CC}
V_{CC} , GND current / pin	I_{CC} or I_{GND}	± 100	mA	
Maximum power dissipation at $T_a = 55^\circ\text{C}$ (in still air) ³	P_T	1	W	TSSOP TVSOP
Storage temperature range	T_{stg}	-65 to 150	$^\circ\text{C}$	

Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating condition" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

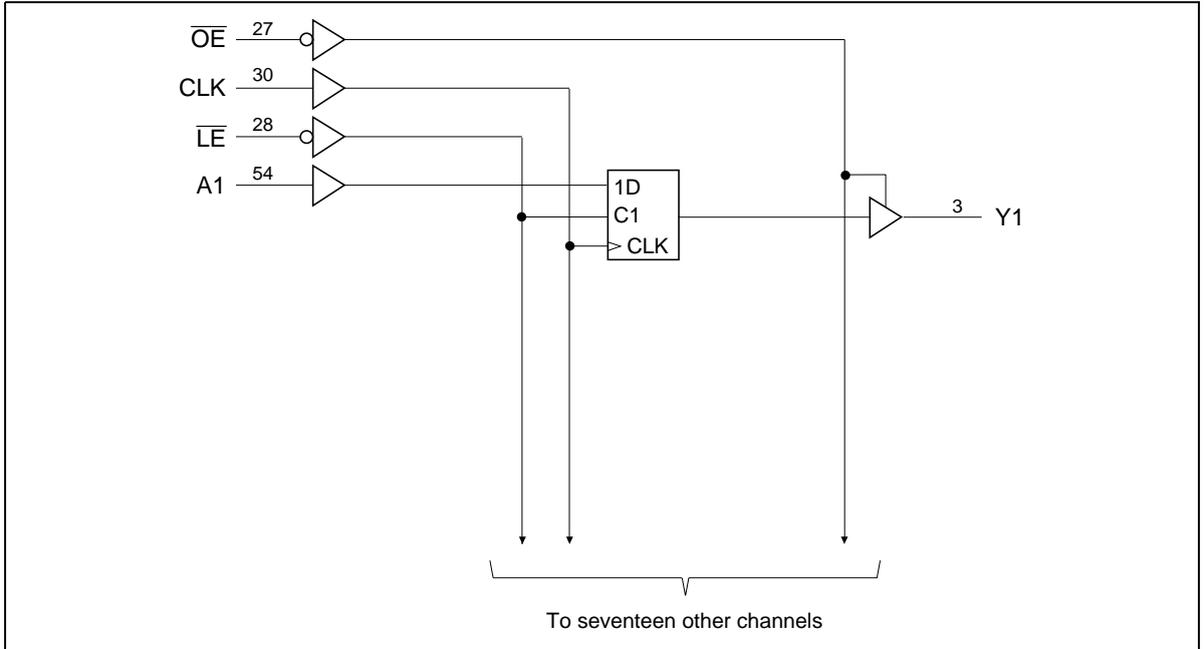
- Notes:
1. The input and output negative-voltage ratings may be exceeded if the input and output clamp current ratings are observed.
 2. The input and output positive-voltage ratings may be exceeded up to 4.6 V if the input and output clamp-current ratings are observed.
 3. The maximum power dissipation is calculated using a junction temperature of 150 $^\circ\text{C}$ and board trace length of 750 mils.

Recommended Operating Conditions

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage	V_{CC}	2.3	3.6	V	
Input voltage	V_I	0	V_{CC}	V	
Output voltage	V_O	0	V_{CC}	V	
High-level output current	I_{OH}	—	-6	mA	$V_{CC} = 2.3\text{ V}$
		—	-8		$V_{CC} = 2.7\text{ V}$
		—	-12		$V_{CC} = 3.0\text{ V}$
Low-level output current	I_{OL}	—	6	mA	$V_{CC} = 2.3\text{ V}$
		—	8		$V_{CC} = 2.7\text{ V}$
		—	12		$V_{CC} = 3.0\text{ V}$
Input transition rise or fall rate	$\bullet t/\blacktriangledown v$	0	10	ns/V	
Operating free-air temperature	T_a	-40	85	$^\circ\text{C}$	

Note: Unused or floating control pins must be held high or low.

Logic Diagram



Electrical Characteristics

Item	Symbol	V_{CC} (V)	$T_a = -40 \text{ to } 85^\circ\text{C}$		Unit	Test Conditions
			Min	Max		
Input voltage	V_{IH}	2.3 to 2.7	1.7	—	V	
		2.7 to 3.6	2.0	—		
	V_{IL}	2.3 to 2.7	—	0.7	V	
		2.7 to 3.6	—	0.8		
Output voltage	V_{OH}	2.3 to 3.6	$V_{CC}-0.2$	—	V	$I_{OH} = -100 \mu\text{A}$
		2.3	1.9	—		$I_{OH} = -4 \text{ mA}, V_{IH} = 1.7 \text{ V}$
		2.3	1.7	—		$I_{OH} = -6 \text{ mA}, V_{IH} = 1.7 \text{ V}$
		3.0	2.4	—		$I_{OH} = -6 \text{ mA}, V_{IH} = 2.0 \text{ V}$
		2.7	2.0	—		$I_{OH} = -8 \text{ mA}, V_{IH} = 2.0 \text{ V}$
		3.0	2.0	—		$I_{OH} = -12 \text{ mA}, V_{IH} = 2.0 \text{ V}$
	V_{OL}	2.3 to 3.6	—	0.2	V	$I_{OL} = 100 \mu\text{A}$
		2.3	—	0.4		$I_{OL} = 4 \text{ mA}, V_{IL} = 0.7 \text{ V}$
		2.3	—	0.55		$I_{OL} = 6 \text{ mA}, V_{IL} = 0.7 \text{ V}$
		3.0	—	0.55		$I_{OL} = 6 \text{ mA}, V_{IL} = 0.8 \text{ V}$
		2.7	—	0.6		$I_{OL} = 8 \text{ mA}, V_{IL} = 0.8 \text{ V}$
		3.0	—	0.8		$I_{OL} = 12 \text{ mA}, V_{IL} = 0.8 \text{ V}$
Input current	I_{IN}	3.6	—	± 5.0	μA	$V_{IN} = V_{CC}$ or GND
Off state output current	I_{OZ}	3.6	—	± 10	μA	$V_{OUT} = V_{CC}$ or GND
Quiescent supply current	I_{CC}	3.6	—	40	μA	$V_{IN} = V_{CC}$ or GND
	ΔI_{CC}	3.0 to 3.6	—	750	μA	One input at $(V_{CC}-0.6)\text{V}$, other inputs at V_{CC} or GND

Switching Characteristics

(Ta = -40 to 85°C)

Item	Symbol	V _{cc} (V)	Min	Typ	Max	Unit	From (Input)	To (Output)		
Maximum clock frequency	f _{max}	2.5±0.2	150	—	—	MHz				
		2.7	150	—	—					
		3.3±0.3	150	—	—					
Propagation delay time	t _{PLH}	2.5±0.2	1.0	—	5.0	ns	A	Y		
		2.7	—	—	5.0					
		3.3±0.3	1.0	—	4.2					
	t _{PHL}	2.5±0.2	1.4	—	6.3		LE	Y		
		2.7	—	—	6.1					
		3.3±0.3	1.4	—	5.4					
		2.5±0.2	1.4	—	6.3				CLK	Y
		2.7	—	—	6.1					
		3.3±0.3	1.4	—	5.4					
Output enable time	t _{ZH}	2.5±0.2	1.4	—	6.3	ns	OE	Y		
		2.7	—	—	6.5					
		3.3±0.3	1.1	—	5.5					
Output disable time	t _{HZ}	2.5±0.2	1.0	—	4.7	ns	OE	Y		
		2.7	—	—	4.9					
		3.3±0.3	1.3	—	4.5					
Input capacitance	C _{IN}	3.3	3.3	4.0	4.5	pF	Control inputs			
		3.3	3.0	6.0	9.0		Data inputs			
Output capacitance	C _O	3.3	3.0	7.0	9.0	pF	Y ports			

Switching Characteristics

(Ta = -40 to 85°C) (cont)

Item	Symbol	V _{cc} (V)	Min	Typ	Max	Unit	From (Input)	
Setup time	t _{su}	2.5±0.2	2.2	—	—	ns	Data before CLK↑	
		2.7	2.1	—	—			
		3.3±0.3	1.7	—	—			
	Data before LE↑	2.5±0.2	1.2	—	—		Data before LE↑	
			2.7	1.6	—		—	
			3.3±0.3	1.3	—		—	
		2.5±0.2	1.4	—	—		Data before LE↑	
			2.7	1.5	—		—	CLK "L"
			3.3±0.3	1.2	—		—	
Hold time	t _h	2.5±0.2	0.6	—	—	ns	Data after CLK↑	
		2.7	0.6	—	—			
		3.3±0.3	0.7	—	—			
	2.5±0.2	1.2	—	—		Data after LE↑		
		2.7	1.1	—		—	CLK "H" or "L"	
		3.3±0.3	1.1	—		—		
Pulse width	t _w	2.5±0.2	3.3	—	—	ns	LE "L"	
		2.7	3.3	—	—			
		3.3±0.3	3.3	—	—			
	2.5±0.2	3.3	—	—		CLK "H" or "L"		
		2.7	3.3	—		—		
		3.3±0.3	3.3	—		—		

Switching Characteristics

(Ta = 0 to 85°C)

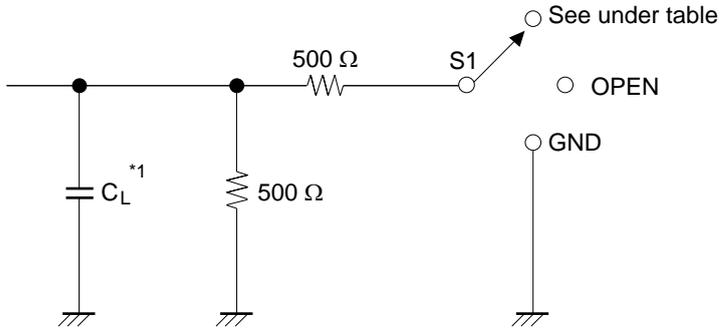
Item	Symbol	V _{cc} (V)	Min	Typ	Max	Unit	FROM (Input)	TO (Output)	
Propagation delay time	C _L =50pF	t _{PLH} , t _{PHL}	3.3±0.3	1.4	—	3.5	ns	CLK	Y
		C _L =30pF	3.3±0.3	0.7	—	2.5		CLK	Y
Setup time	t _{su}	3.3±0.3	1.0	—	—	ns	Data before CLK↑		
Hold time	t _h	3.3±0.3	0.6	—	—	ns	Data after CLK↑		

Operating Characteristics

(Ta = 25°C)

Item	Symbol	$V_{cc} = 2.5 \pm 0.2 \text{ V}$	$V_{cc} = 3.3 \pm 0.3 \text{ V}$	Unit	Test Conditions	
		Typ	Typ			
Power dissipation capacitance	Outputs enable	C_{pd}	22.0	24.5	pF	$C_L = 0, f = 10 \text{ MHz}$
	Outputs disable		5.0	6.0		

Test Circuit

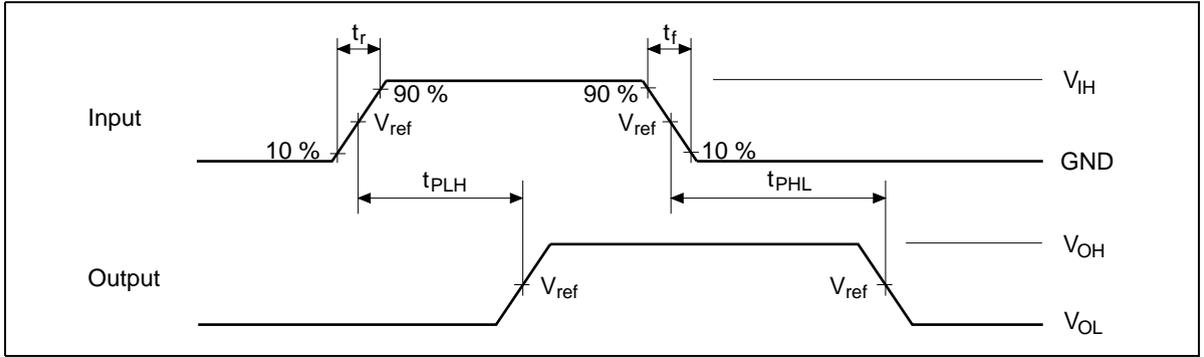


Load Circuit for Outputs

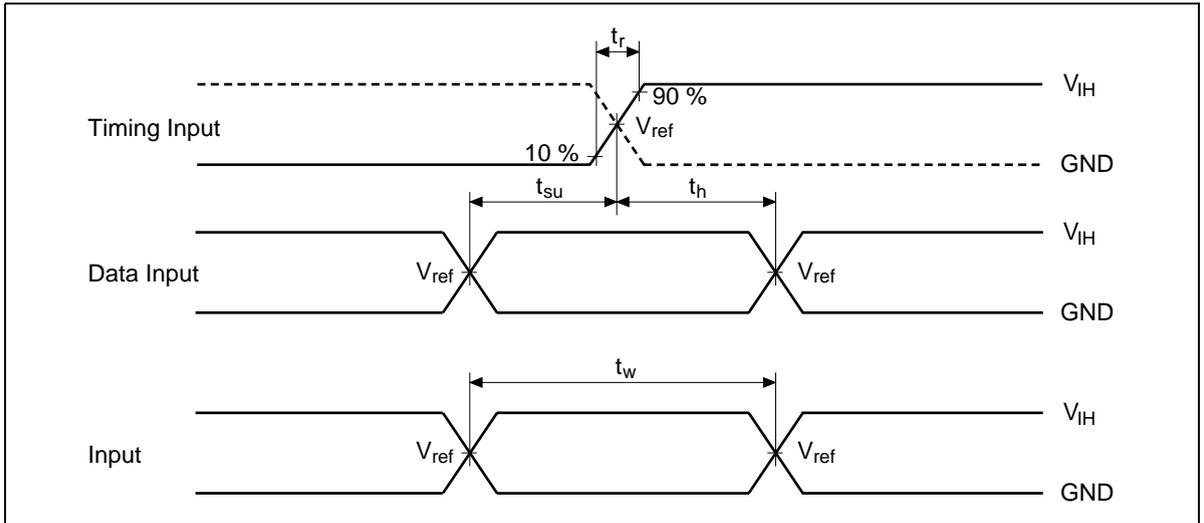
Symbol	$V_{CC}=2.5\pm 0.2V$	$V_{CC}=2.7V,$ $3.3\pm 0.3V$
t_{PLH}/t_{PHL}	OPEN	OPEN
$t_{su}/t_h/t_w$		
t_{ZH}/t_{HZ}	GND	GND
t_{ZL}/t_{LZ}	$2 \times V_{CC}$	6.0 V
C_L	30 pF	50 pF

Note: 1. C_L includes probe and jig capacitance.

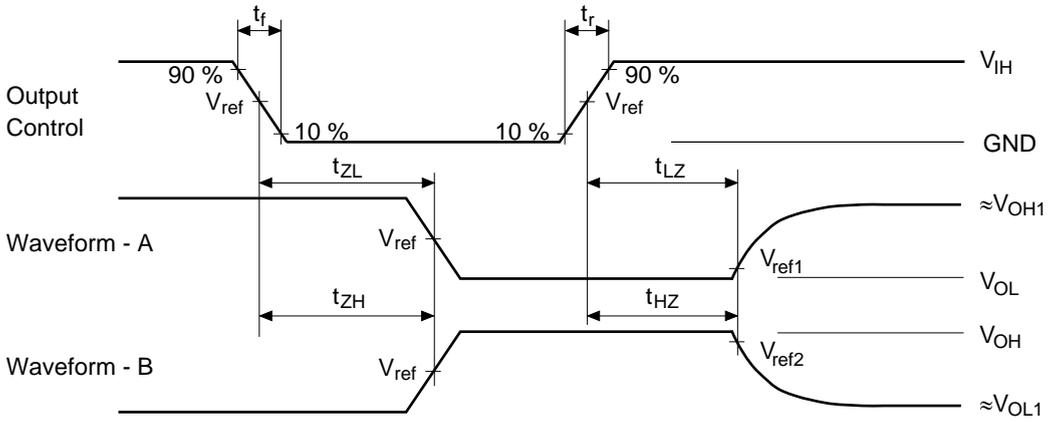
Waveforms – 1



Waveforms – 2



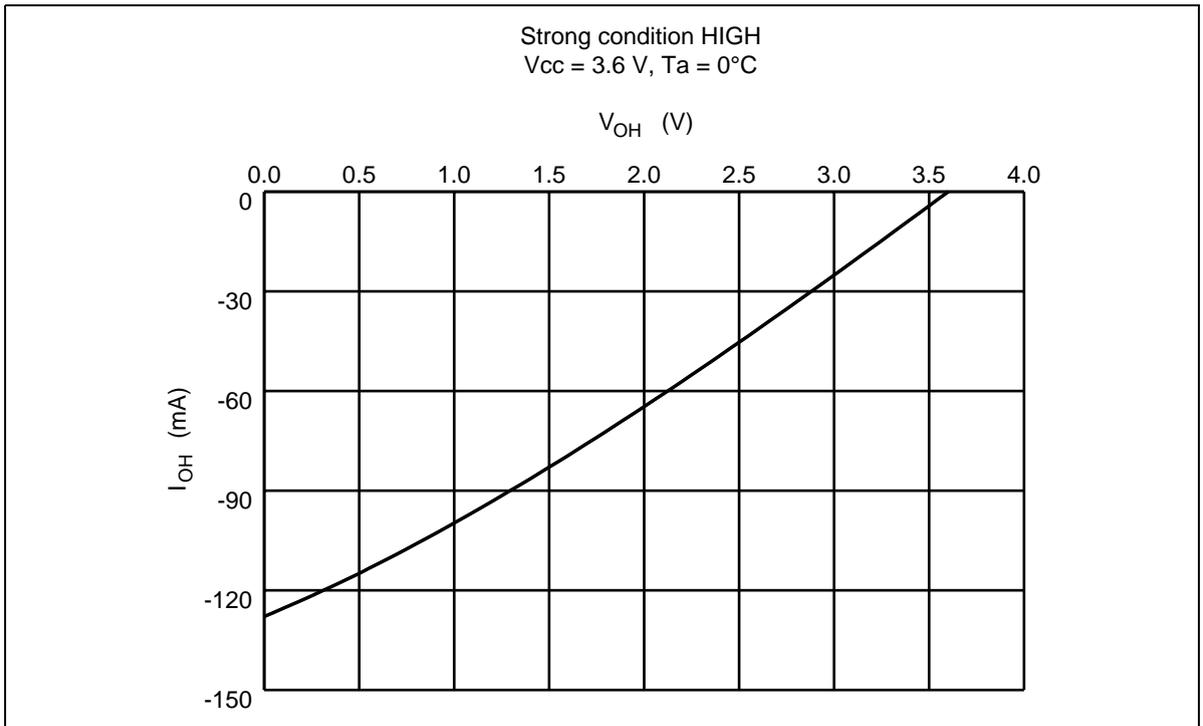
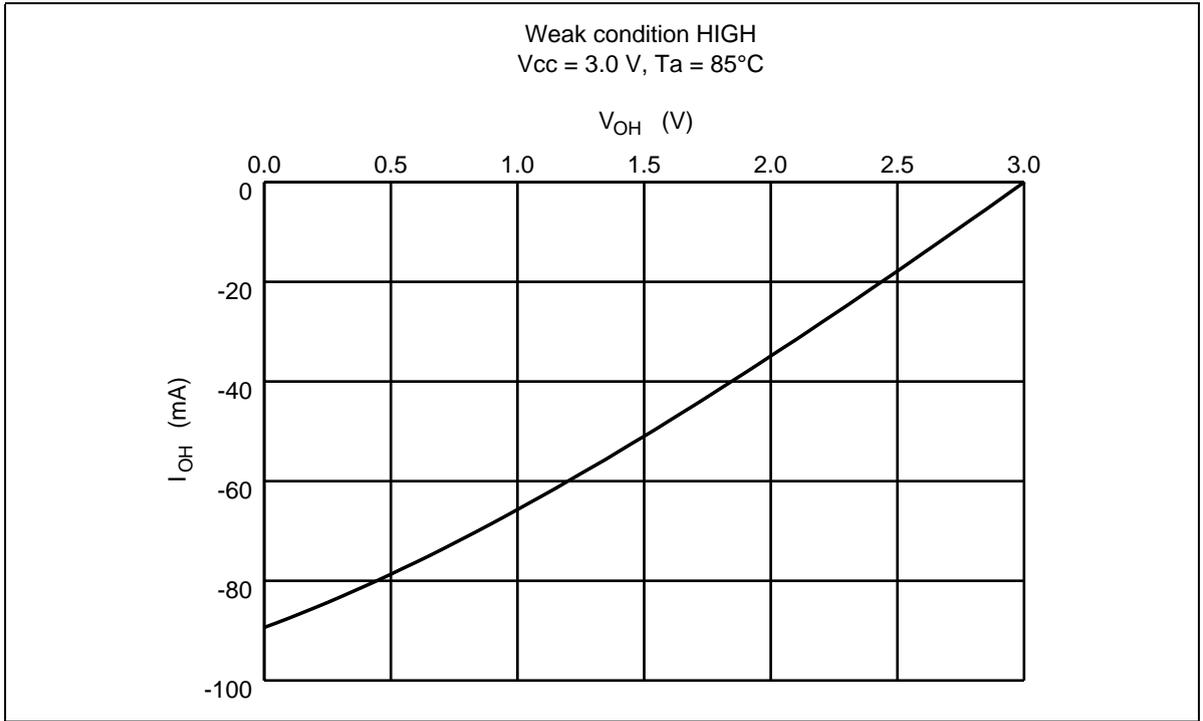
Waveforms – 3



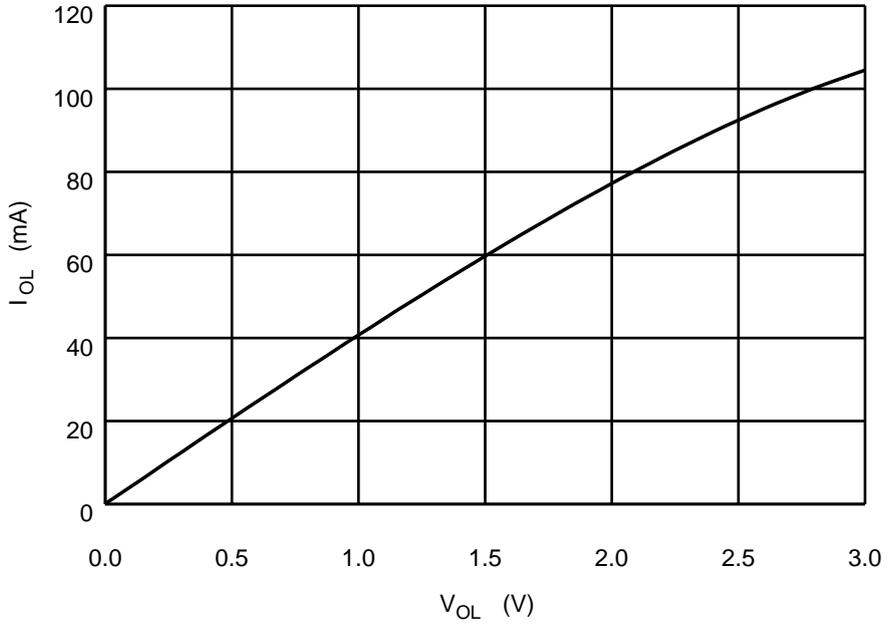
TEST	$V_{CC}=2.5\pm 0.2V$	$V_{CC}=2.7V, 3.3\pm 0.3V$
V_{IH}	V_{CC}	2.7 V
V_{ref}	$1/2 V_{CC}$	1.5 V
V_{ref1}	$V_{OL} + 0.15 V$	$V_{OL} + 0.3 V$
V_{ref2}	$V_{OH} - 0.15 V$	$V_{OH} - 0.3 V$
V_{OH1}	V_{CC}	3.0 V
V_{OL1}	GND	GND

- Notes:
- All input pulses are supplied by generators having the following characteristics :
 PRR • 10 MHz, $Z_o = 50 \Omega$, $t_r \bullet 2.0 \text{ ns}$, $t_f \bullet 2.0 \text{ ns}$. ($V_{CC} = 2.5\pm 0.2 V$)
 PRR • 10 MHz, $Z_o = 50 \Omega$, $t_r \bullet 2.5 \text{ ns}$, $t_f \bullet 2.5 \text{ ns}$. ($V_{CC} = 2.7 V, 3.3\pm 0.3 V$)
 - Waveform – A is for an output with internal conditions such that the output is low except when disabled by the output control.
 - Waveform – B is for an output with internal conditions such that the output is high except when disabled by the output control.
 - The output are measured one at a time with one transition per measurement.

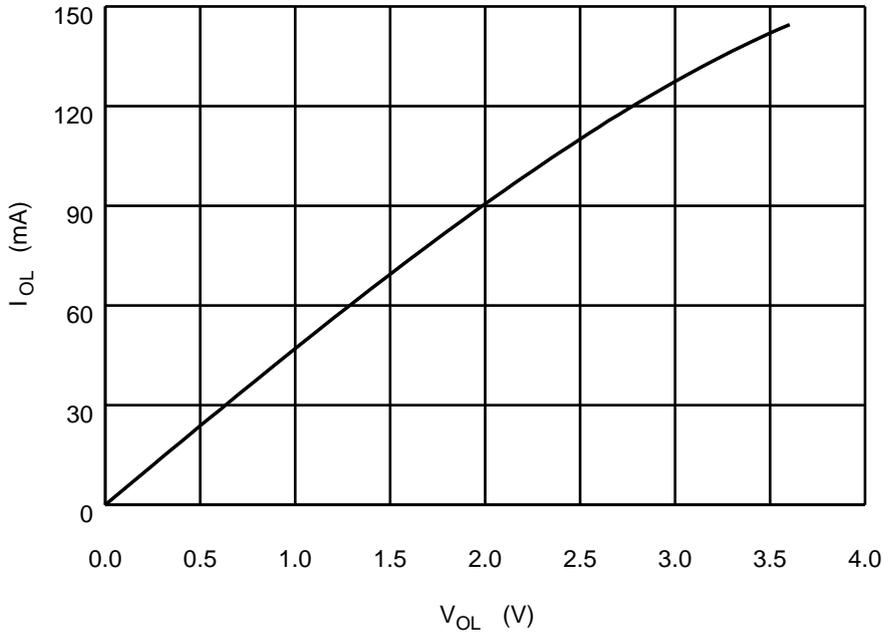
IV Characteristics for Register Output (Measured value)



Weak condition LOW
 $V_{CC} = 3.0\text{ V}$, $T_a = 85^\circ\text{C}$

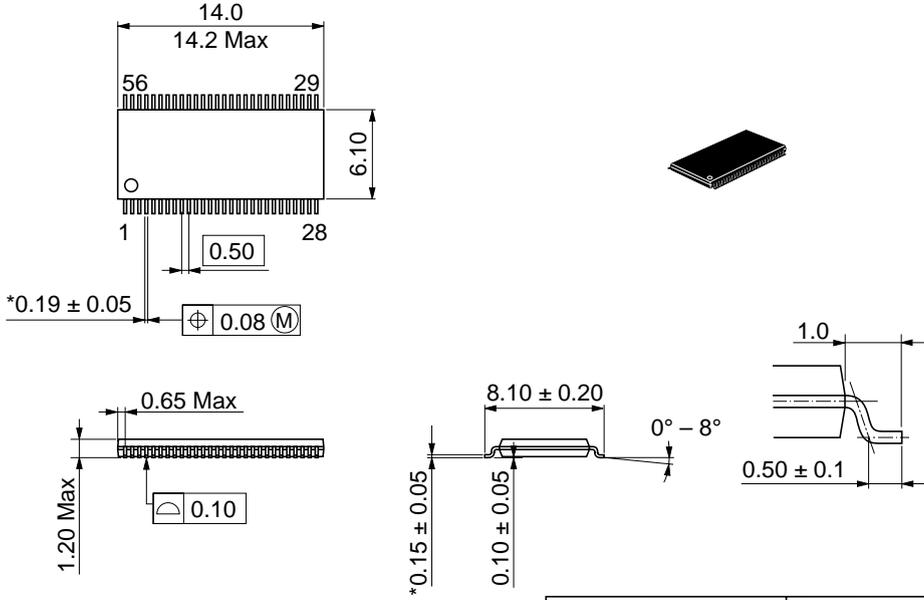


Strong condition LOW
 $V_{CC} = 3.6\text{ V}$, $T_a = 0^\circ\text{C}$



Package Dimensions

As of July, 2001
Unit: mm

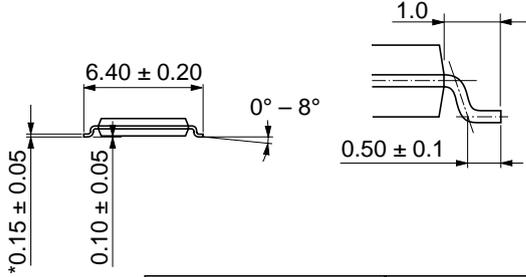
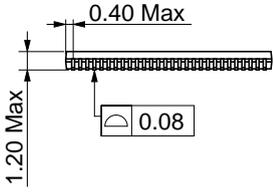
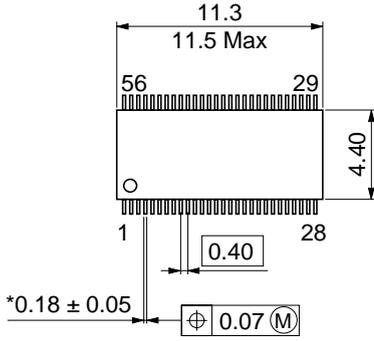


*Pd plating

Hitachi Code	TTP-56DAV
JEDEC	—
JEITA	—
Mass (reference value)	0.32 g

HD74ALVC162834A

As of July, 2001
Unit: mm



*Pd plating

Hitachi Code	TTP-56DBV
JEDEC	—
JEITA	—
Mass (reference value)	—

Cautions

1. Hitachi neither warrants nor grants licenses of any rights of Hitachi's or any third party's patent, copyright, trademark, or other intellectual property rights for information contained in this document. Hitachi bears no responsibility for problems that may arise with third party's rights, including intellectual property rights, in connection with use of the information contained in this document.
2. Products and product specifications may be subject to change without notice. Confirm that you have received the latest product standards or specifications before final design, purchase or use.
3. Hitachi makes every attempt to ensure that its products are of high quality and reliability. However, contact Hitachi's sales office before using the product in an application that demands especially high quality and reliability or where its failure or malfunction may directly threaten human life or cause risk of bodily injury, such as aerospace, aeronautics, nuclear power, combustion control, transportation, traffic, safety equipment or medical equipment for life support.
4. Design your application so that the product is used within the ranges guaranteed by Hitachi particularly for maximum rating, operating supply voltage range, heat radiation characteristics, installation conditions and other characteristics. Hitachi bears no responsibility for failure or damage when used beyond the guaranteed ranges. Even within the guaranteed ranges, consider normally foreseeable failure rates or failure modes in semiconductor devices and employ systemic measures such as fail-safes, so that the equipment incorporating Hitachi product does not cause bodily injury, fire or other consequential damage due to operation of the Hitachi product.
5. This product is not designed to be radiation resistant.
6. No one is permitted to reproduce or duplicate, in any form, the whole or part of this document without written approval from Hitachi.
7. Contact Hitachi's sales office for any questions regarding this document or Hitachi semiconductor products.

Sales offices

HITACHI

Hitachi, Ltd.

Semiconductor & Integrated Circuits
Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan
Tel: (03) 3270-2111 Fax: (03) 3270-5109

URL <http://www.hitachisemiconductor.com/>

For further information write to:

Hitachi Semiconductor (America) Inc. 179 East Tasman Drive San Jose, CA 95134 Tel: <1> (408) 433-1990 Fax: <1>(408) 433-0223	Hitachi Europe Ltd. Electronic Components Group Whitebrook Park Lower Cookham Road Maidenhead Berkshire SL6 8YA, United Kingdom Tel: <44> (1628) 585000 Fax: <44> (1628) 585200	Hitachi Asia Ltd. Hitachi Tower 16 Collyer Quay #20-00 Singapore 049318 Tel: <65>-538-6533/538-8577 Fax: <65>-538-6933/538-3877 URL: http://semiconductor.hitachi.com.sg	Hitachi Asia (Hong Kong) Ltd. Group III (Electronic Components) 7/F., North Tower World Finance Centre, Harbour City, Canton Road Tsim Sha Tsui, Kowloon Hong Kong Tel: <852>-(2)-735-9218 Fax: <852>-(2)-730-0281 URL: http://semiconductor.hitachi.com.hk
	Hitachi Europe GmbH Electronic Components Group Dornacher Straße 3 D-85622 Feldkirchen Postfach 201, D-85619 Feldkirchen Germany Tel: <49> (89) 9 9180-0 Fax: <49> (89) 9 29 30 00	Hitachi Asia Ltd. (Taipei Branch Office) 4/F, No. 167, Tun Hwa North Road Hung-Kuo Building Taipei (105), Taiwan Tel: <886>-(2)-2718-3666 Fax: <886>-(2)-2718-8180 Tel: 23222 HAS-TP URL: http://www.hitachi.com.tw	

Copyright © Hitachi, Ltd., 2001. All rights reserved. Printed in Japan.
Colophon 5.0